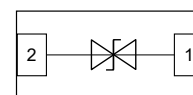


Features

- 95Watts peak pulse power ($t_p = 8/20\mu s$)
- Tiny DFN0603-2 package
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Response time is typically $< 1ns$
- Medium capacitance ($C_j = 15pF$ typ.)
- Protection one data/power line to:
 - IEC 61000-4-2 $\pm 30kV$ contact $\pm 30kV$ air
 - IEC 61000-4-4 (EFT) 40A (5/50ns)
 - IEC 61000-4-5 (Lightning) 8A (8/20 μs)



Mechanical Data

- **Case:** DFN0603-2 (plastic package).
Lead free; RoHS compliant; Halogen free
- **Molding Compound Flammability Rating:**
UL 94 V-0
- **Terminals:** High temperature soldering guaranteed:
260 °C/10 sec. at terminals

Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Absolute Maximum Ratings

Ratings at 25 °C, ambient temperature unless otherwise specified

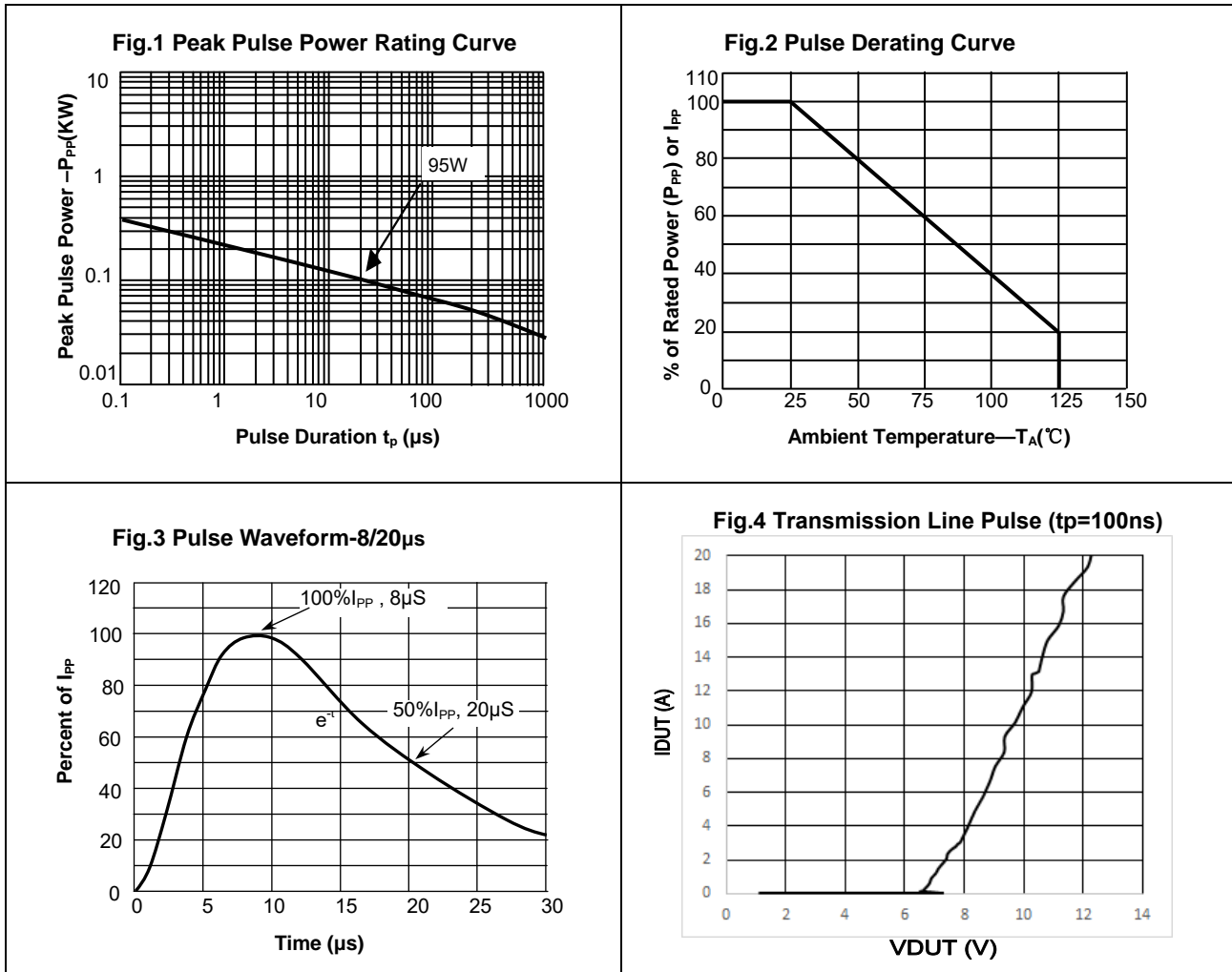
Parameter	Symbol	Value	Unit
Peak Pulse Power ($T_P=8/20\mu S$)	P_{PP}	95	W
ESD contact/air discharge (IEC-61000-4-2)	V_{ESD}	30/30	kV
Peak Pulse Current ($t_P = 8/20\mu S$)	I_{PP}	6	A
Junction Temperature	T_J	-55 to +125	°C
Storage temperature	T_{STG}	-55 to +150	°C
Maximum Lead Solder Temperature(10 second duration)	T_L	260	°C

Electrical Characteristics

($T_A = 25$ °C unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Reverse stand-off Voltage	V_{RWM}				5	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	5.8			V
Reverse Leakage Current	I_R	$V_R=5V$			1	μA
Clamping Voltage(SURGE)	V_C	$I_{PP}=8A, T_P=8/20\mu S$			12	V
Clamping Voltage(ESD)	V_C	$V_{ESD} = +6kV$		8.5		V
Clamping Voltage(TLP)	V_C	$I_{PP}=8A, T_P=100nS$		9		V
Clamping Voltage(TLP)	V_C	$I_{PP}=16A, T_P=100nS$		11		V
Dynamic Resistance	R_{dyn}			0.295		Ω
Junction Capacitance	C_J	$V_R=0V, f=1MHz$		15		pF

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)



Package Dimensions

